## NSN 5961-01-179-5159

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View Online at https://aerobasegroup.com/nsn/5961-01-179-5159 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 475.0 collector to base voltage/static/emitter open and 475.0 collector-to-emitter, substaining voltage, base open-circuited and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 90536-7906012 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

N/a

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